

NCE P-Channel Enhancement Mode Power MOSFET

Description

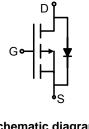
The NCE2305A uses advanced trench technology to provide excellent R_{DS(ON)}, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a load switch or in PWM applications.

General Features

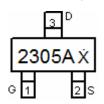
- V_{DS} = -16V,I_D = -4.1A $R_{DS(ON)} < 60m\Omega @ V_{GS}$ =-2.5V $R_{DS(ON)} < 45m\Omega @ V_{GS}=-4.5V$
- High power and current handing capability
- Lead free product is acquired
- Surface mount package

Application

- PWM applications
- Load switch
- Power management



Schematic diagram



Marking and pin Assignment



Package Marking And Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2305A X	NCE2305A	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

- ·	•			
Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	Vds	-16	V	
Gate-Source Voltage	Vgs	±12	V	
Drain Current -Continuous	ID	-4.1	А	
Drain Current -Pulsed (Note 1)	I _{DM}	-15	А	
Maximum Power Dissipation	PD	1.7	W	
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C	

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	R _{0JA}	74	°C/W
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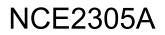
Electrical Characteristics (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-16	-18	-	V



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Parameter	Symbol	Condition	Min	Тур	Max	Unit
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-16V,V _{GS} =0V	-	-	-1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±12V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)			•	•		
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-0.45	-0.7	-1.0	V
Drain-Source On-State Resistance		V _{GS} =-4.5V, I _D =-4.1A	-	29	45	
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-2.5V, I _D =-3A	-	40	60	mΩ
Forward Transconductance	g fs	V _{DS} =-5V,I _D =-4.1A	5	-	-	S
Dynamic Characteristics (Note4)		·		•		
Input Capacitance	C _{lss}	(-4)(-2)(-2)(-2)(-2)(-2)(-2)(-2)(-2)(-2)(-2	-	740	-	PF
Output Capacitance	C _{oss}	- V _{DS} =-4V,V _{GS} =0V, F=1.0MHz	-	290	-	PF
Reverse Transfer Capacitance	C _{rss}		-	190	-	PF
Switching Characteristics (Note 4)		·		•		
Turn-on Delay Time	t _{d(on)}		-	12	-	nS
Turn-on Rise Time	tr	V _{DD} =-4V,I _D =-4.1A ,	-	35	-	nS
Turn-Off Delay Time	t _{d(off)}	R_{L} =-1.2Ω, V_{GEN} =-4.5V, R_{g} =1Ω	-	30	-	nS
Turn-Off Fall Time	t _f	-	-	10	-	nS
Total Gate Charge	Qg		-	7.8	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =-4V,I _D =-4.1A,V _{GS} =-4.5V	-	1.2	-	nC
Gate-Drain Charge	Q _{gd}	1	-	1.6	-	nC
Drain-Source Diode Characteristics	•	•				
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-4.1A	-	-	-1.2	V
Diode Forward Current (Note 2)	I _S		-	-	-4.1	Α

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production



NCE2305A



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Typical Electrical and Thermal Characteristics

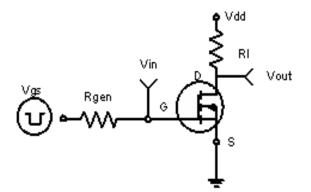
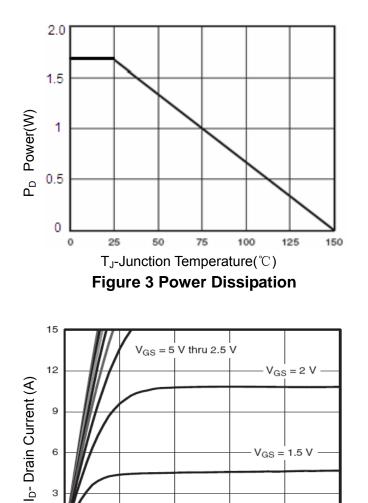


Figure 1:Switching Test Circuit

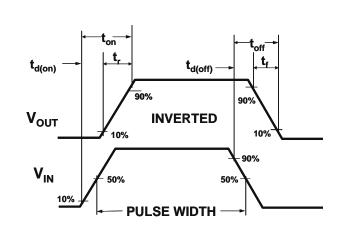


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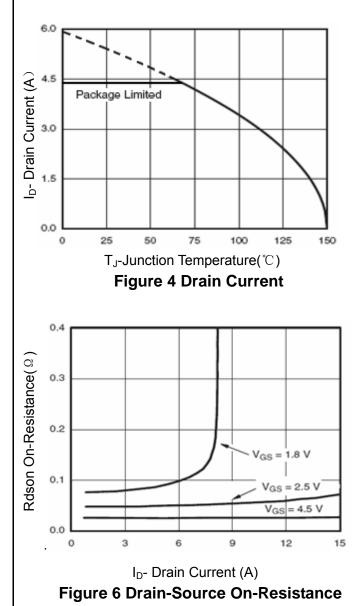
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Vds Drain-Source Voltage (V)

Figure 5 Output Characteristics







1

6

з

0

0

5

V_{GS} = 1.5 V

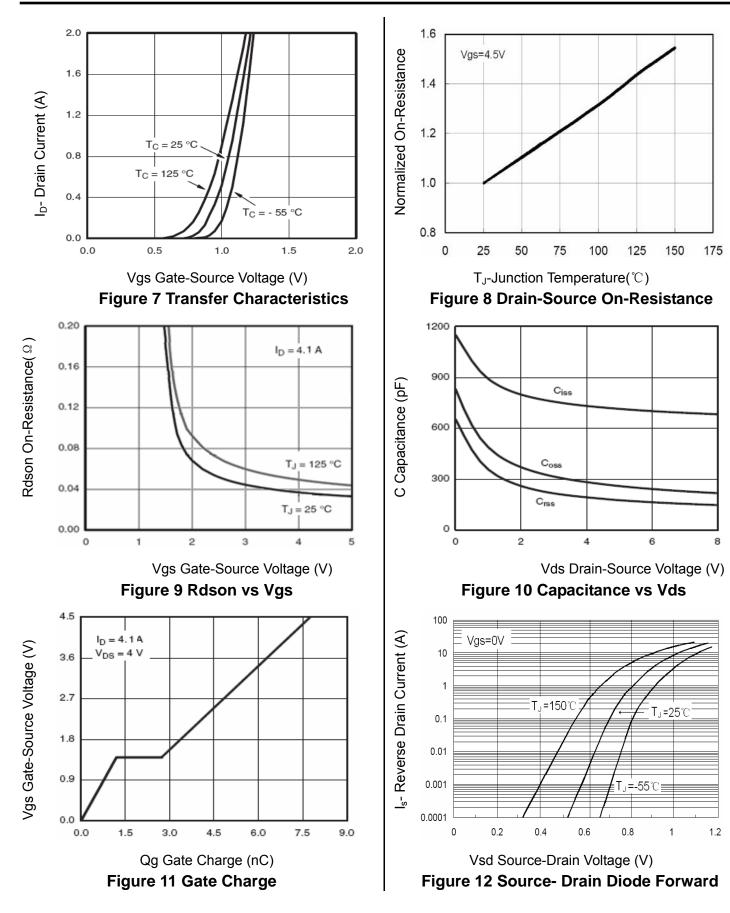
 $V_{GS} = 1 V$



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Pb Free Product

NCE2305A





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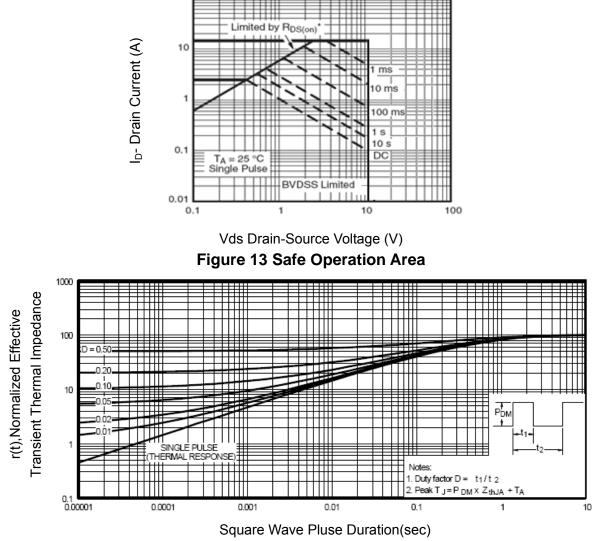


Figure 14 Normalized Maximum Transient Thermal Impedance

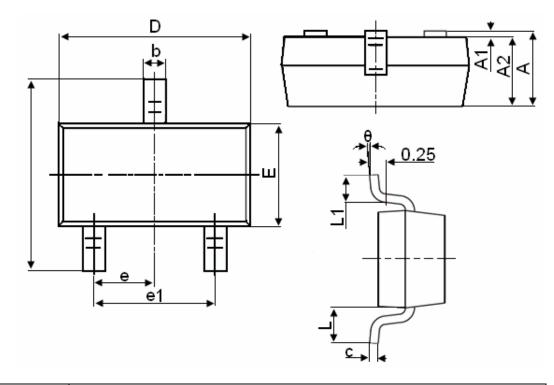


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SOT-23 Package Information



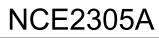
Symbol		Dimensions in Millimeters		
Symbol	MIN.	MAX.		
A	0.900	1.150		
A1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
с	0.080	0.150		
D	2.800	3.000		
E	1.200	1.400		
E1	2.250	2.550		
е		0.950TYP		
e1	1.800	2.000		
L		0.550REF		
L1	0.300	0.500		
θ	0°	8°		

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.







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